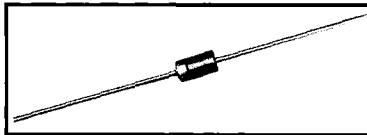


**1 AMP. GLASS PASSIVATED JUNCTION  
PLASTIC SILICON RECTIFIERS**



**VOLTAGE RANGE**  
50 to 1000 Volts  
**CURRENT**  
1.0 Ampere

### FEATURES

- Glass passivated chip
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Freon, Alcohol, Chlorothene and similar solvents
- The plastic material carries U/L recognition 94V-0

### MECHANICAL DATA

Case: Molded Plastic

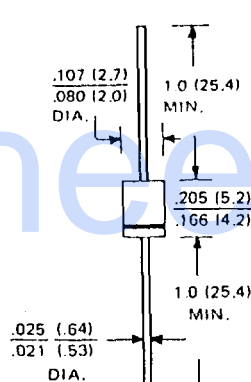
Terminals: Plated axial leads, solderable per MIL-STD-202, Method 208

Polarity: Color band denotes cathode

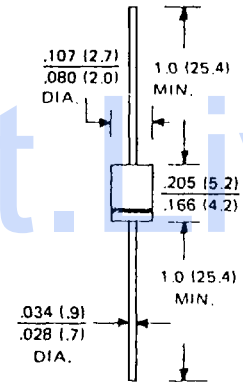
Weight: 0.012 ounce, 0.3 grams

Mounting position: Any

### 1N4000GL A-405



### 1N4000G DO-41



All dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25° C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load,

For capacitive load, derate current by 20%.

		1N4001GL	1N4002GL	1N4003GL	1N4004GL	1N4005GL	1N4006GL	1N4007GL	UNITS
		1N4001G	1N4002G	1N4003G	1N4004G	1N4005G	1N4006G	1N4007G	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Lengths @ $T_A = 75^\circ C$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current 8.3 ms single half-sine-wave superimposed on rated load	$I_{FSM}$	30							A
Maximum Forward Voltage at 1.0A DC	$V_F$	1.0							V
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 125^\circ C$	$I_R$	5 50							$\mu A$ $\mu A$
Typical Junction Capacitance (Note 1)	$C_J$	8							$\mu F$
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	45							$^\circ C/W$
Maximum Reverse Recovery Time (Note 3)	$T_{RR}$	2							$\mu S$
Operating and Storage Temperature Range	$T_{STG}$	-65 to +175							$^\circ C$

NOTES: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC

2. Thermal Resistance Junction to Ambient.

3. Reverse Recovery Test Conditions:  $I_F = 0.5A$ ,  $I_R = 1A$ ,  $I_{rr} = 0.25A$ .

FIG. 1 - TYPICAL FORWARD CHARACTERISTIC

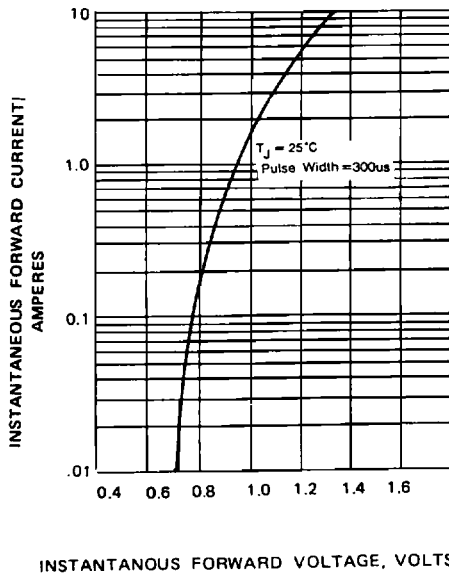


FIG. 2 - FORWARD DERATING CURVE

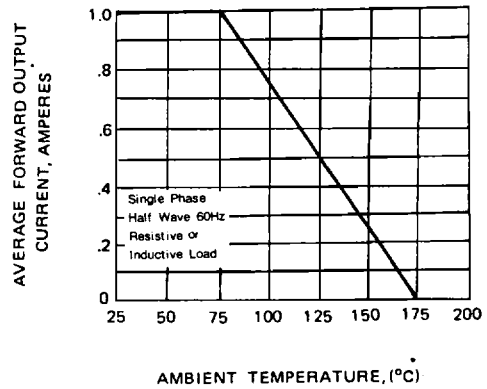


FIG. 4 - TYPICAL JUNCTION CAPACITANCE

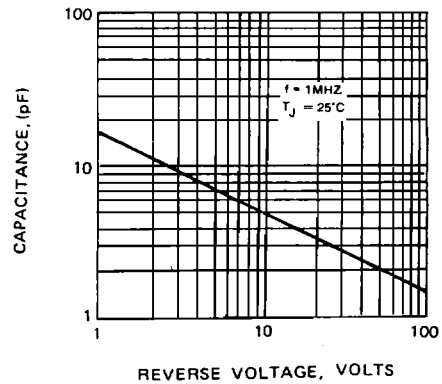


FIG. 3 - PEAK FORWARD SURGE CURRENT

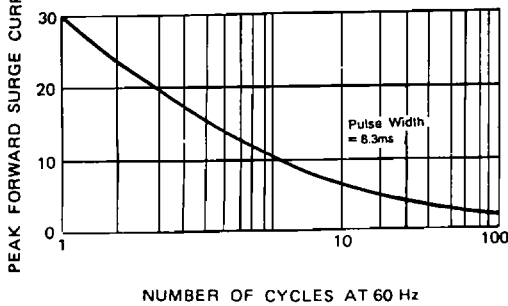


FIG. 5 - TYPICAL REVERSE CHARACTERISTICS

